

TOSHIBA Field Effect Transistor Silicon N Channel Dual Gate MOS Type

3SK226

TV Tuner, VHF RF Amplifier Applications

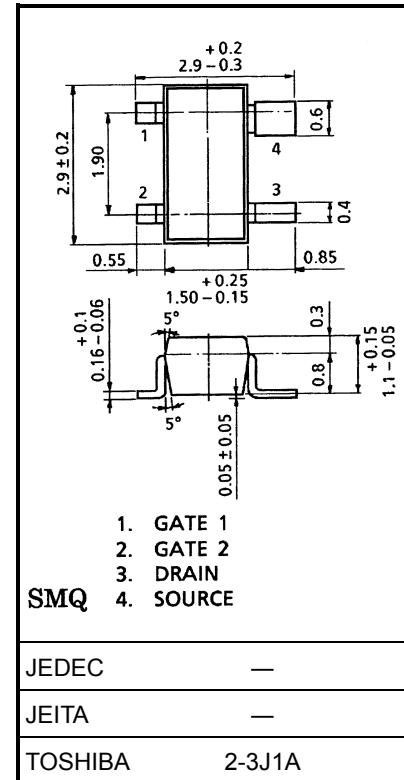
FM Tuner Applications

Unit: mm

- Superior cross modulation performance.
- Low reverse transfer capacitance: $C_{rss} = 0.015$ pF (typ.)
- Low noise figure: NF = 1.1dB (typ.)

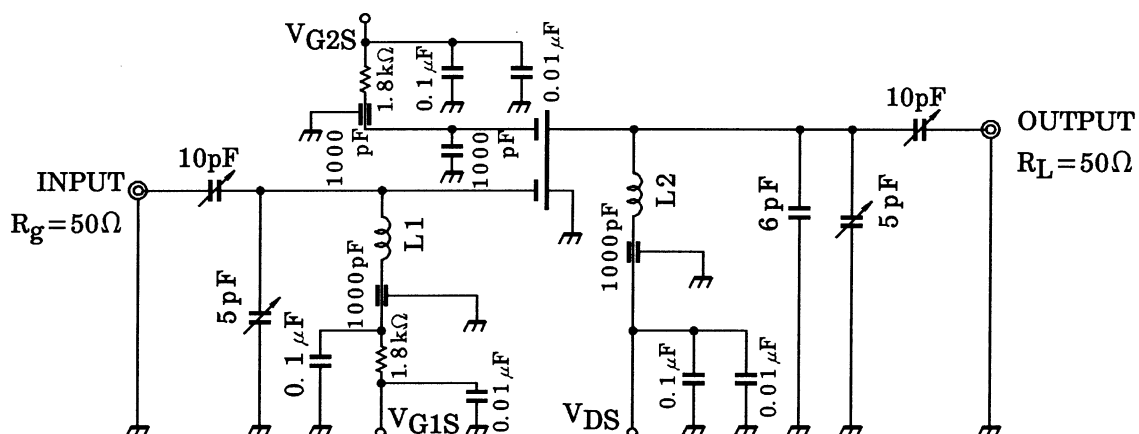
Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	13.5	V
Gate 1-source voltage	V_{G1S}	± 8	V
Gate 2-source voltage	V_{G2S}	± 8	V
Drain current	I_D	30	mA
Drain power dissipation	P_D	150	mW
Channel temperature	T_{ch}	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	$-55\sim 125$	$^\circ\text{C}$

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Weight: 0.013 g (typ.)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate 1 leakage current	I_{G1SS}	$V_{DS} = 0, V_{G1S} = \pm 6 \text{ V}, V_{G2S} = 0$	—	—	± 50	nA
Gate 2 leakage current	I_{G2SS}	$V_{DS} = 0, V_{G1S} = 0, V_{G2S} = \pm 6 \text{ V}$	—	—	± 50	nA
Drain-source voltage	$V_{(BR)DSX}$	$V_{G1S} = -4 \text{ V}, V_{G2S} = -4 \text{ V}, I_D = 100 \mu\text{A}$	13.5	—	—	V
Drain current	I_{DSS}	$V_{DS} = 6 \text{ V}, V_{G1S} = 0, V_{G2S} = 4.5 \text{ V}$	0	—	0.1	mA
Gate 1-source cut-off voltage	$V_{G1S(OFF)}$	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 100 \mu\text{A}$	0	—	1.0	V
Gate 2-source cut-off voltage	$V_{G2S(OFF)}$	$V_{DS} = 6 \text{ V}, V_{G1S} = 4 \text{ V}, I_D = 100 \mu\text{A}$	0.5	1.0	1.5	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 10 \text{ mA}, f = 1 \text{ kHz}$	—	13	—	mS
Input capacitance	C_{iss}	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 10 \text{ mA}, f = 1 \text{ MHz}$	2.1	2.7	3.3	pF
Reverse transfer capacitance	C_{rss}		—	0.015	0.03	pF
Power gain	G_{ps}	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 10 \text{ mA}, f = 200 \text{ MHz (Figure 1)}$	23	27	—	dB
Noise figure	NF		—	1.1	2.2	dB

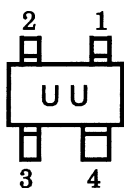


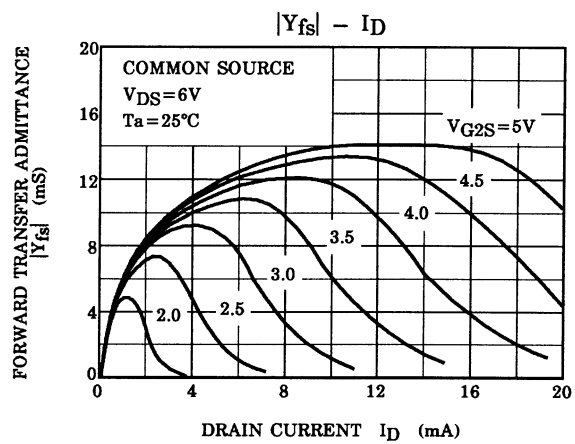
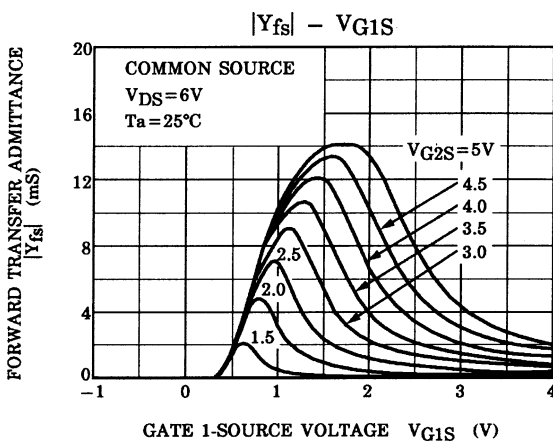
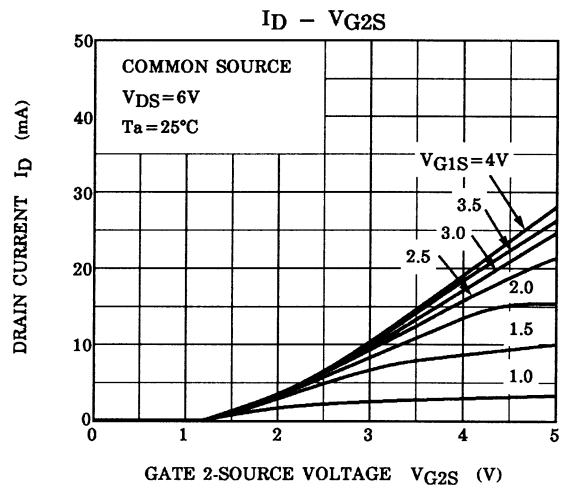
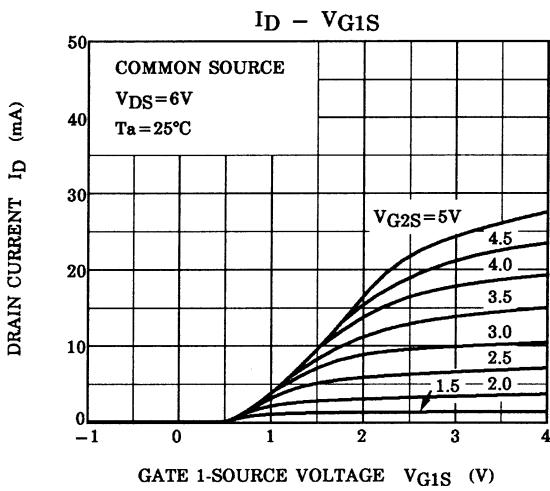
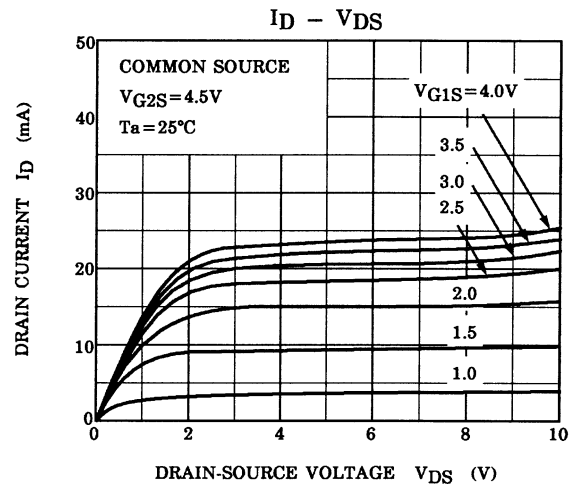
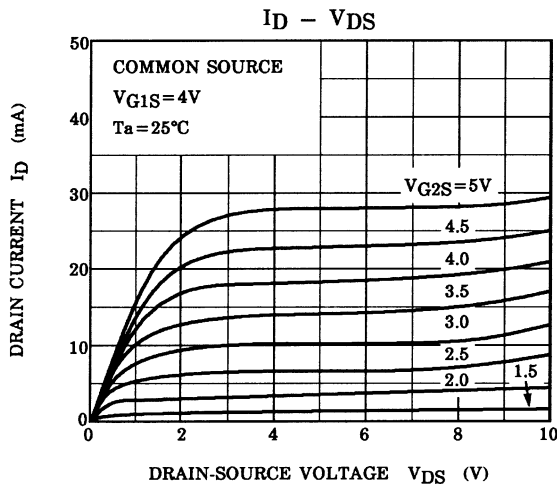
L1: 1 mmφ Ag plated copper wire, 2 turns, 8 mm ID

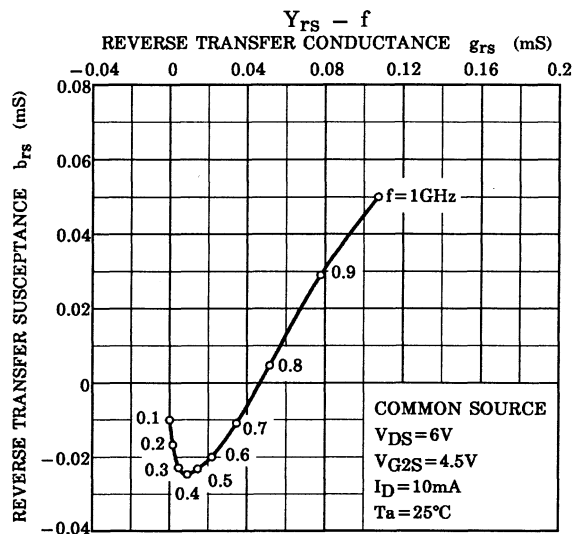
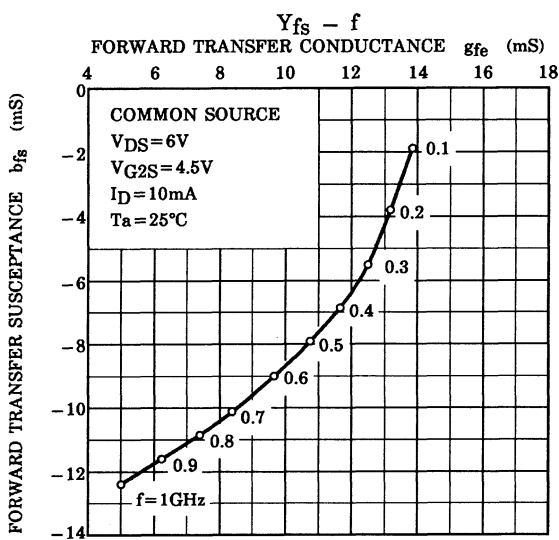
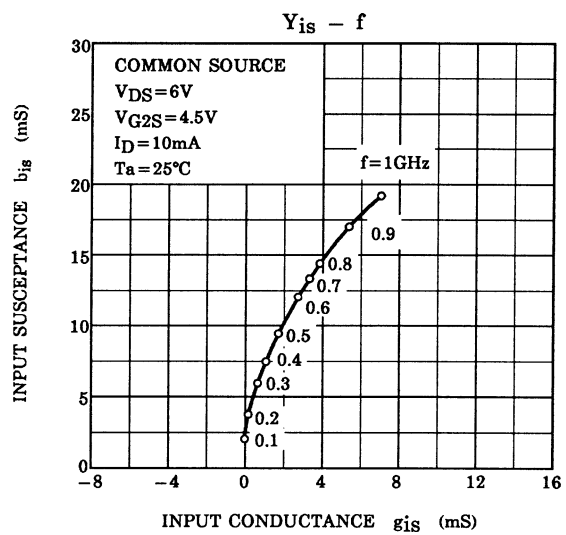
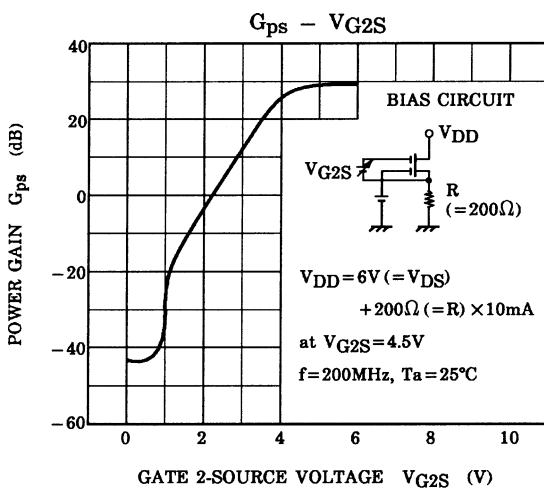
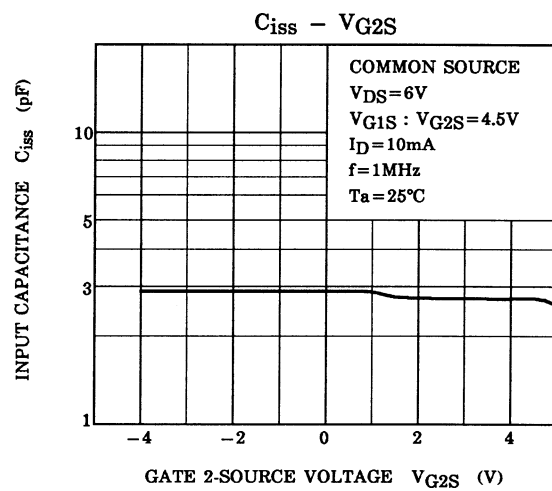
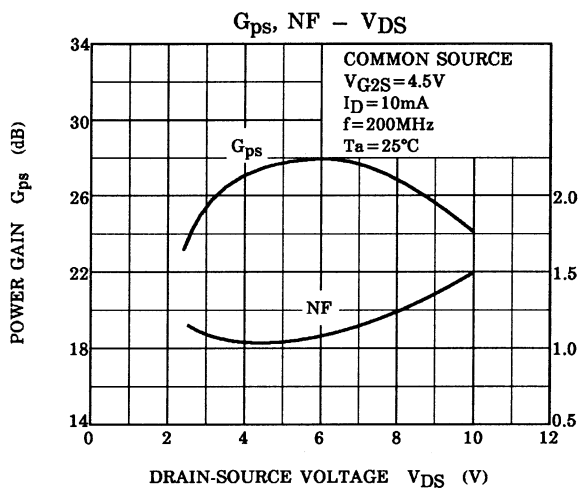
L2: 1 mmφ Ag plated copper wire, 2.5 turns, 8 mm ID

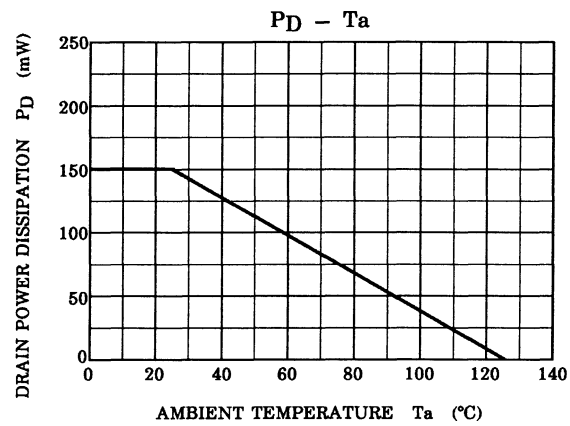
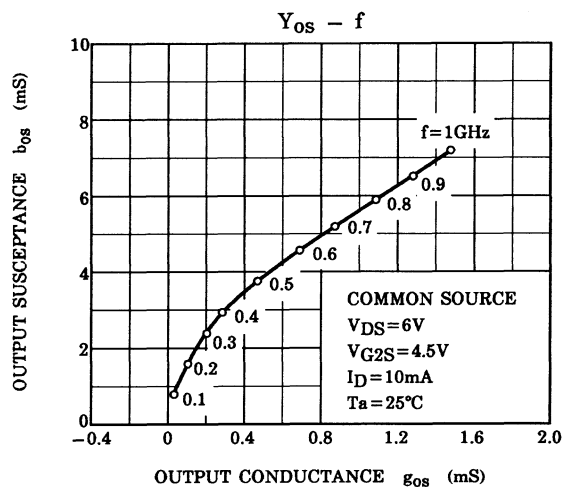
Figure 1 200 MHz, G_{ps} NF Test Circuit

Marking









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